NSN 5962-01-085-3471

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View Online at https://aerobasegroup.com/nsn/5962-01-085-3471

Between 0.740 inches and 0.810 inches

Body Width:

Between 0.280 inches and 0.300 inches

Body Height:

Between 0.144 inches and 0.179 inches

Maximum Power Dissipation Rating:

475.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and monolithic and positive outputs and 3-state output and programmable and programmed and bipolar and w/enable and w/decoded output and schottky and high speed and w/buffered output and w/disable and w/storage

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Terminal Surface Treatment:

Gold

Voltage Rating And Type Per Characteristic:

5.5 volts power source

Time Rating Per Chacteristic:

85.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Precious Material And Location:

Terminal surfaces gold

Precious Material:

Gold

Test Data Document:

13499-390-0073 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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